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Product specification





FEATURES

- Very Small Plastic Package
- High Switching Speed

Reference News

APPLICATIONS

 High-Speed Switching in e.g. Surface Mounted Circuits

PACKAGE OUTLINE	PIN CONFIGURATION	Marking
SOD-323		A6

MAXIMUM RATINGS (Ta=25 $^{\circ}$ C unless otherwise noted)

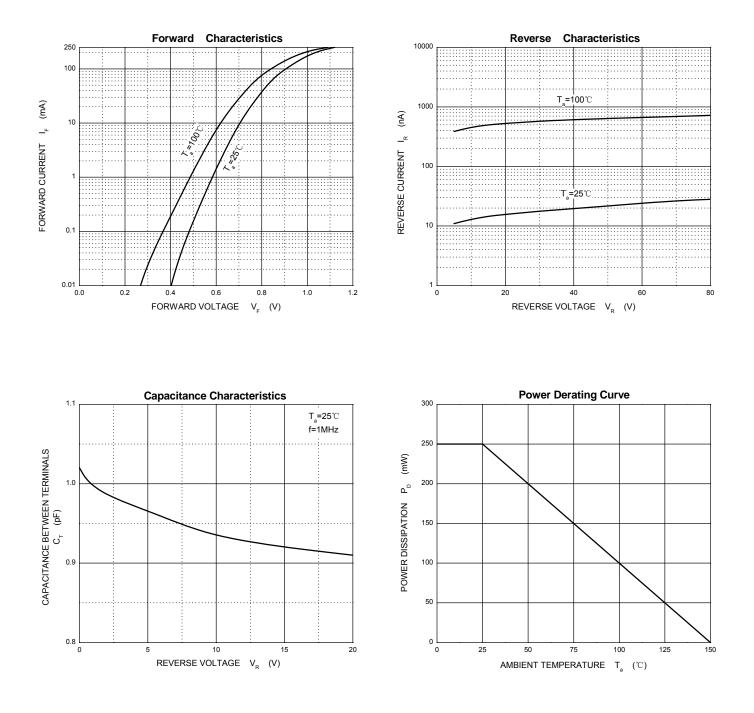
Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage 85		V	
VR	DC Blocking Voltage	75	V	
lo	Continuous Forward Current	250	mA	
IFSM	Non-repetitive Peak Forward SurgeCurrent@t= 8.3ms	2.0	A	
PD	Power Dissipation	250	mW	
R _{0JA}	Thermal Resistance from Junction to Ambient	500	°C/W	
TJ,Tstg	Operation Junction an Storage Temperature Range	-55~+150	°C	

ELECTRICAL CHARACTERISTICS(Ta=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Reverse voltage	V _(BR)	I _R =100μA	100			V
		V _R =25V			30	nA
Reverse current	lR	V _R =75V			1	μA
Forward voltage	VF	l⊧=1mA			0.715	V
		l⊧=10mA			0.855	
		l⊧=50mA			1	
		l⊧=150mA			1.25	
Total capacitance	Ctot	V _R =0V,f=1MHz			1.5	pF
Reverse recovery time	trr	I⊧= I _R =10mA, I _{rr} =0.1×I _R			4	ns

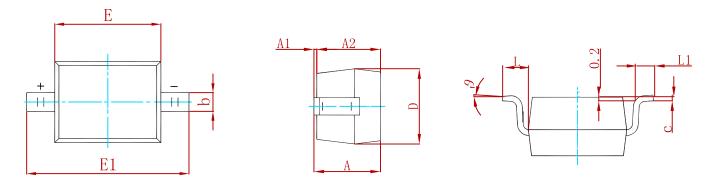
BAS316





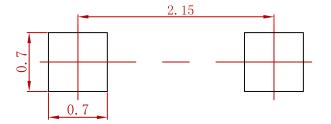


PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
A		1.000		0.039
A 1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
с	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.550	2.750	0.100	0.108
L	0.475	REF.	0.019	REF.
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters. 2.General tolerance:±0.05mm. 3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
BAS316	SOD-323	3000



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